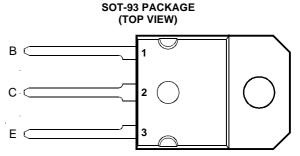
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- Designed for Complementary Use with TIP145, TIP146 and TIP147
- 125 W at 25°C Case Temperature
- 10 A Continuous Collector Current
- Minimum h_{FE} of 1000 at 4 V, 5 A



Pin 2 is in electrical contact with the mounting base.

MDTRAA

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING			VALUE	UNIT	
	TIP140		60		
Collector-base voltage ($I_E = 0$)	TIP141	V _{CBO}	80	V	
	TIP142		100		
	TIP140		60		
Collector-emitter voltage ($I_B = 0$)	TIP141	V _{CEO}	80	V	
	TIP142		100		
Emitter-base voltage			5	V	
Continuous collector current			10	A	
Peak collector current (see Note 1)			15	A	
Continuous base current			0.5	A	
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			125	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)			3.5	W	
Unclamped inductive load energy (see Note 4)			100	mJ	
Operating junction temperature range			-65 to +150	°C	
Storage temperature range			-65 to +150	°C	
Lead temperature 3.2 mm from case for 10 seconds			260	°C	

NOTES: 1. This value applies for $t_p \leq 0.3$ ms, duty cycle $\leq 10\%.$

2. Derate linearly to 150°C case temperature at the rate of 1 W/°C.

3. Derate linearly to 150°C free air temperature at the rate of 28 mW/°C.

4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH, $I_{B(on)}$ = 5 mA, R_{BE} = 100 Ω , $V_{BE(off)}$ = 0, R_S = 0.1 Ω , V_{CC} = 20 V.





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electrical characteristics at 25°C case temperature

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
V _{(BR)CEO}	Collector-emitter breakdown voltage	I _C = 30 mA (see Note 5)	I _B = 0	TIP140 TIP141 TIP142	60 80 100			V
I _{CEO}	Collector-emitter cut-off current	$V_{CE} = 30 V$ $V_{CE} = 40 V$ $V_{CE} = 50 V$	$I_{B} = 0$ $I_{B} = 0$ $I_{B} = 0$	TIP140 TIP141 TIP142			2 2 2	mA
I _{CBO}	Collector cut-off current	$V_{CB} = 60 V$ $V_{CB} = 80 V$ $V_{CB} = 100 V$	I _E = 0 I _E = 0 I _E = 0	TIP140 TIP141 TIP142			1 1 1	mA
I _{EBO}	Emitter cut-off current	V _{EB} = 5 V	I _C = 0				2	mA
h _{FE}	Forward current transfer ratio	$V_{CE} = 4 V$ $V_{CE} = 4 V$	I _C = 5 A I _C = 10 A	(see Notes 5 and 6)	1000 500			
V _{CE(sat)}	Collector-emitter saturation voltage	$I_B = 10 \text{ mA}$ $I_B = 40 \text{ mA}$	I _C = 5 A I _C = 10 A	(see Notes 5 and 6)			2 3	V
V _{BE}	Base-emitter voltage	V _{CE} = 4 V	I _C = 10 A	(see Notes 5 and 6)			3	V
V _{EC}	Parallel diode forward voltage	I _E = 10 A	I _B = 0	(see Notes 5 and 6)			3.5	V

NOTES: 5. These parameters must be measured using pulse techniques, t_p = 300 µs, duty cycle \leq 2%.

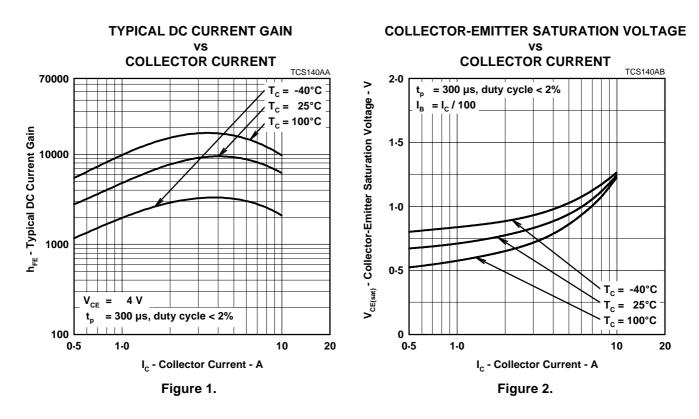
6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

resistive-load-switching characteristics at 25°C case temperature

	PARAMETER	TEST CONDITIONS [†]			MIN	ТҮР	MAX	UNIT
t _{on}	Turn-on time	I _C = 10 A	$I_{B(on)} = 40 \text{ mA}$	$I_{B(off)} = -40 \text{ mA}$		0.9		μs
t _{off}	Turn-off time	$V_{BE(off)}$ = -4.2 V	$R_L = 3 \Omega$	t_p = 20 µs, dc \leq 2%		11		μs

[†] Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

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TYPICAL CHARACTERISTICS

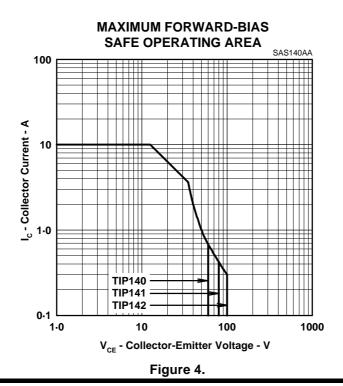
BASE-EMITTER SATURATION VOLTAGE vs **COLLECTOR CURRENT** TCS140AC 3.0 $T_c = -40^{\circ}C$ $V_{BE(sat)}$ - Base-Emitter Saturation Voltage - V $T_c = 25^{\circ}C$ T_c = 100°C 2.5 2.0 1.5 1.0 0.5 = I_c / 100 I, = 300 µs, duty cycle < 2% t, 0 1.0 0.5 10 20 I_c - Collector Current - A



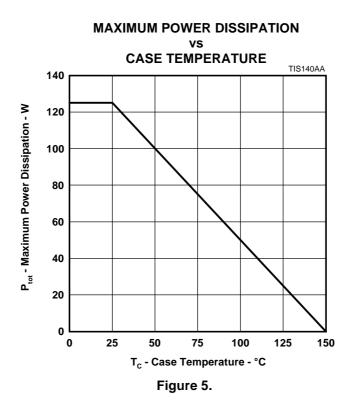


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MAXIMUM SAFE OPERATING REGIONS







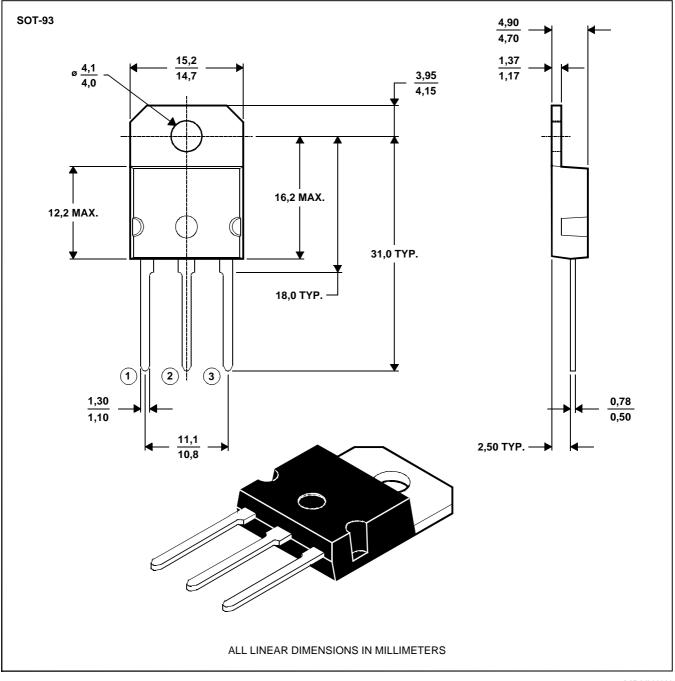
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MECHANICAL DATA

SOT-93

3-pin plastic flange-mount package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTE A: The centre pin is in electrical contact with the mounting tab.

MDXXAW

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